

C4532JB3A103M200KA

TDK Item Description : C4532JB3A103MT****



Application & Main Feature

Commercial Grade (High Voltage (1000V and over))

Series

C4532 [EIA CC1812]



Dimensions

L 4.50mm +/-0.4mm
 W 3.20mm +/-0.4mm
 T 2.00mm +/-0.2mm
 B 0.20mm Min.
 G

Temperature Characteristic

JB (-25 to 85 degC +/-10%)

Rated Voltage

3A (1000Vdc)

Capacitance

10nF

Capacitance Tolerance

M (+/-20%)

Dissipation Factor

3% Max.

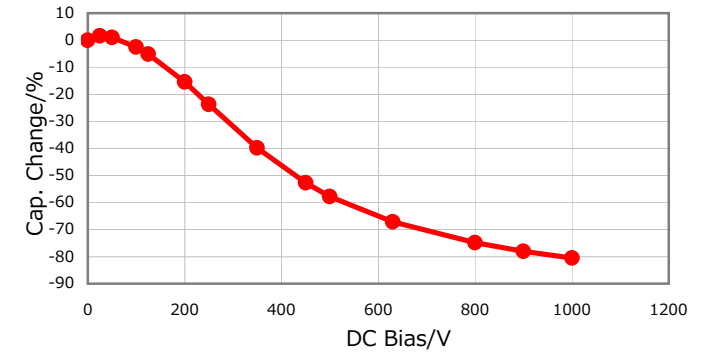
Insulation Resistance

10Gohm Min.

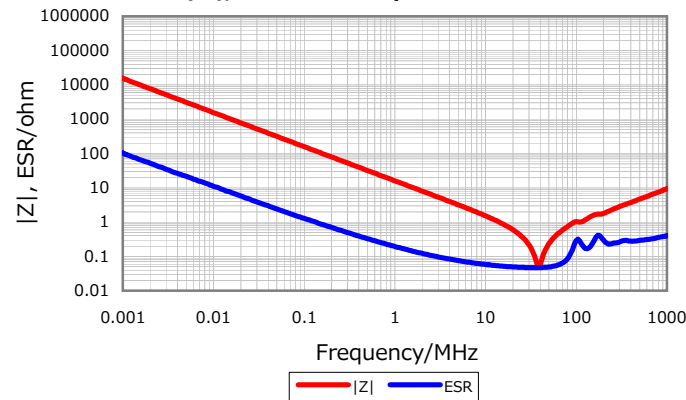
AEC-Q200

Not Applicable

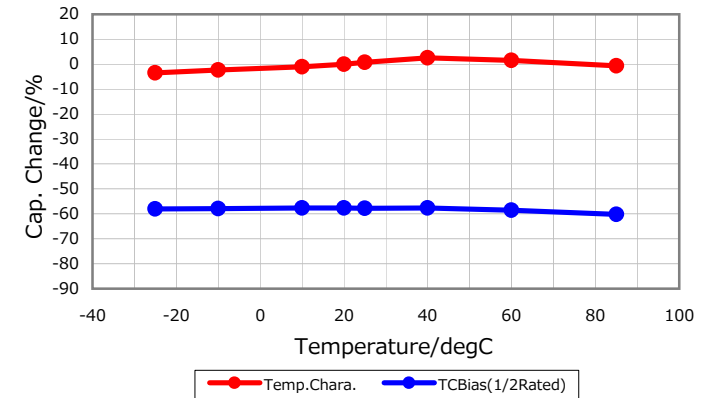
DC Bias Characteristic



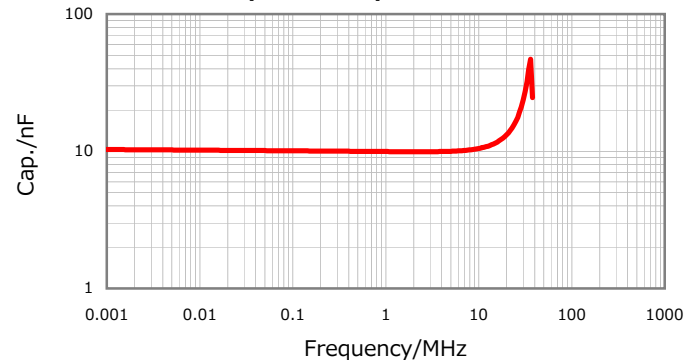
|Z|, ESR vs. Freq. Characteristics



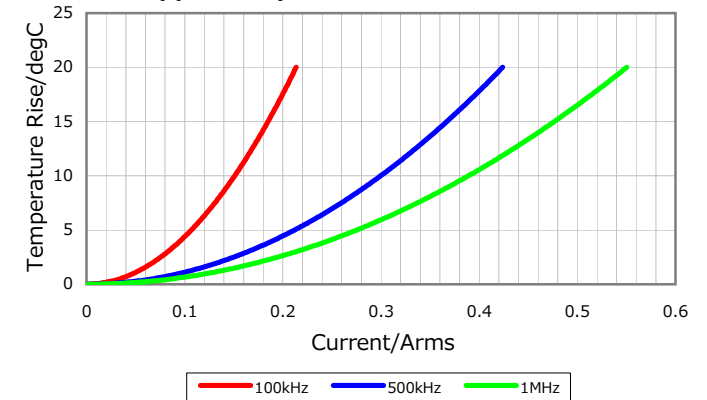
Temperature Characteristics



Cap. vs. Freq. Characteristic



Ripple Temperature Rise Characteristics



Characterization Sheet (Multilayer Ceramic Chip Capacitors)



All specifications are subject to change without notice.

January 4, 2016